

Development of a Low-Noise Front-end ASIC for CdTe Detectors

Tenyo Kawamura ^a, Tadashi Orita ^a, Shin'ichiro Takeda ^a,
Shin Watanabe ^b, Hirokazu Ikeda ^b, Tadayuki Takahashi ^a

^a Kavli IPMU, University of Tokyo

^b ISAS, JAXA

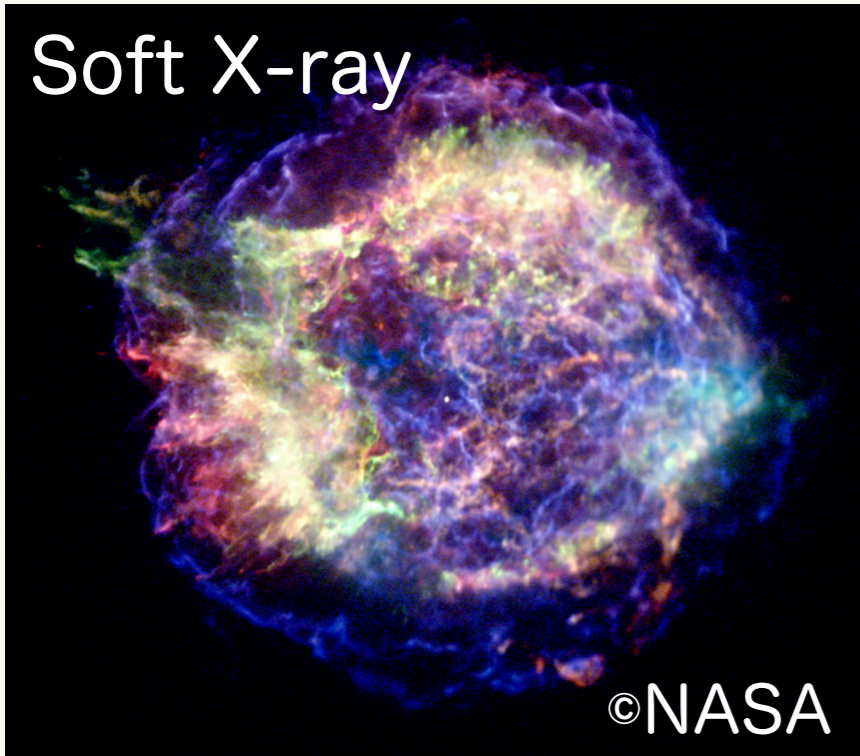
December 18, 2019

12th International “Hiroshima” Symposium on the Development and Application of
Semiconductor Tracking Detectors (HSTD12) at Hiroshima, Japan

X-ray and Gamma-ray Imaging with Spectroscopy

Astrophysics

Soft X-ray



Red: 0.5 keV-1.5 keV
Green: 1.5 keV-2.5 keV
Blue: 4.0 keV-6.0 keV

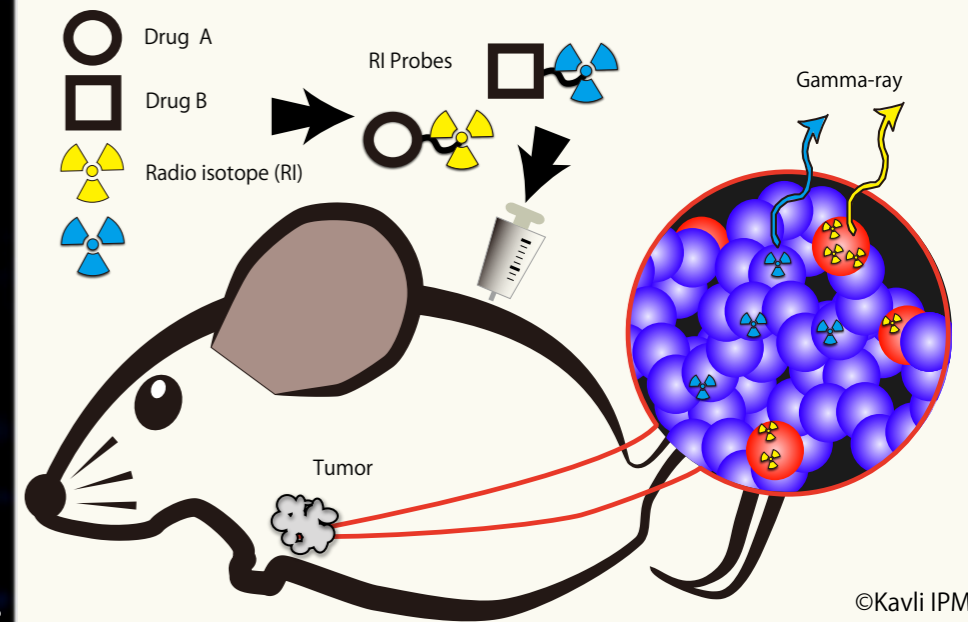
Hard X-ray



Red: 15 keV-20 keV
Green: 20 keV-25 keV
Blue: 25 keV-35 keV

Nuclear Medicine

In vivo imaging

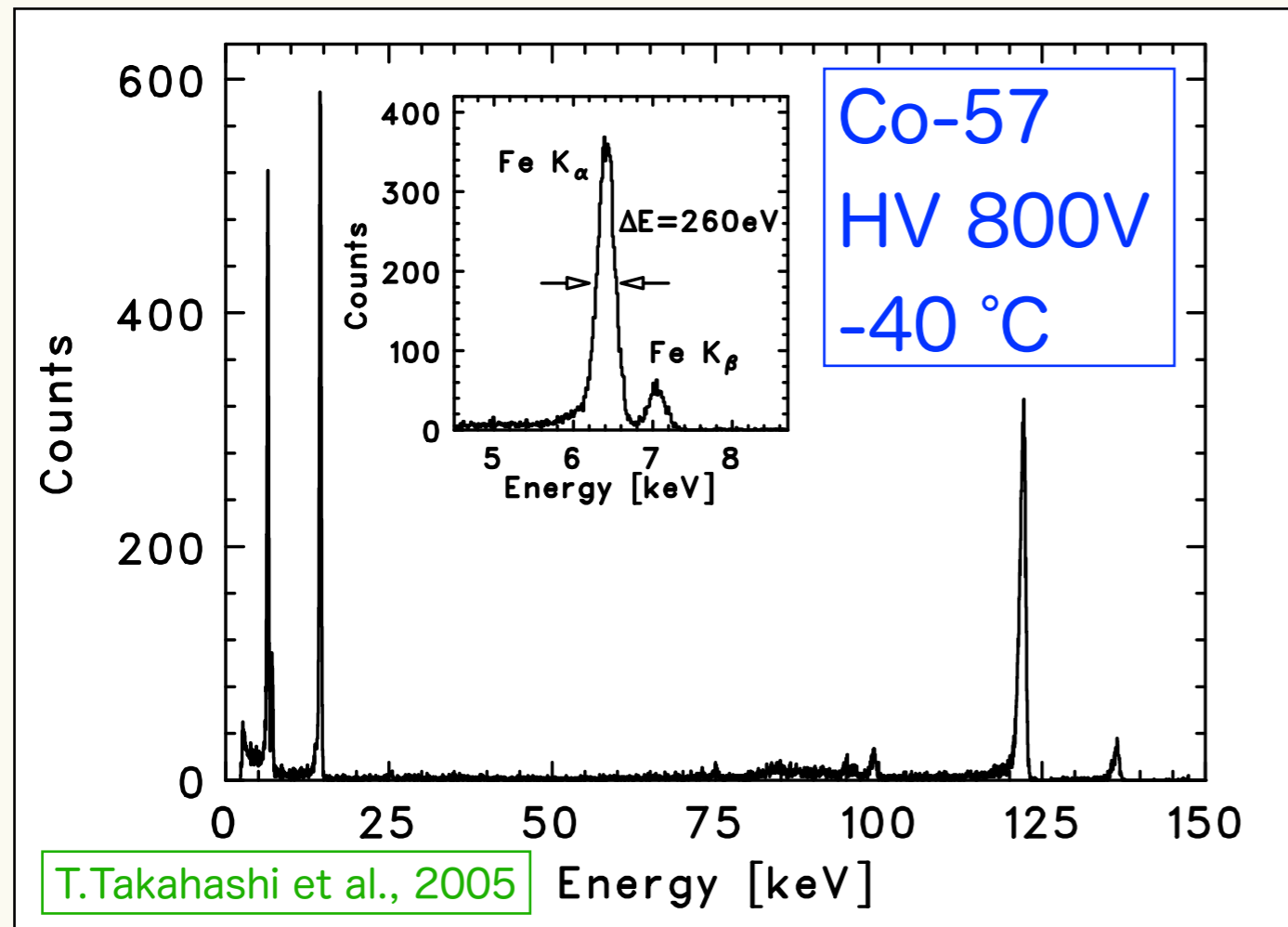


We need to separate spectrum in multi-nuclide.
(^{111}In , ^{125}I , $^{99\text{m}}\text{Tc}$)

Good energy resolution is crucial for hard X-ray and gamma-ray imaging.

For realizing Imaging with good spectroscopy

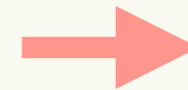
Our best spectrum with CdTe



- CdTe
 - ▶ 3mm x 3mm
 - ▶ 1mm thickness
- Front-end ASIC
 - ▶ Only one readout chain
 - ▶ Only analog circuit (CSA and Shaper)

Our goal is to extend readout channels, keeping high spectroscopic capability:

- Resolution ~ 1 keV
- Threshold ~ 5 keV

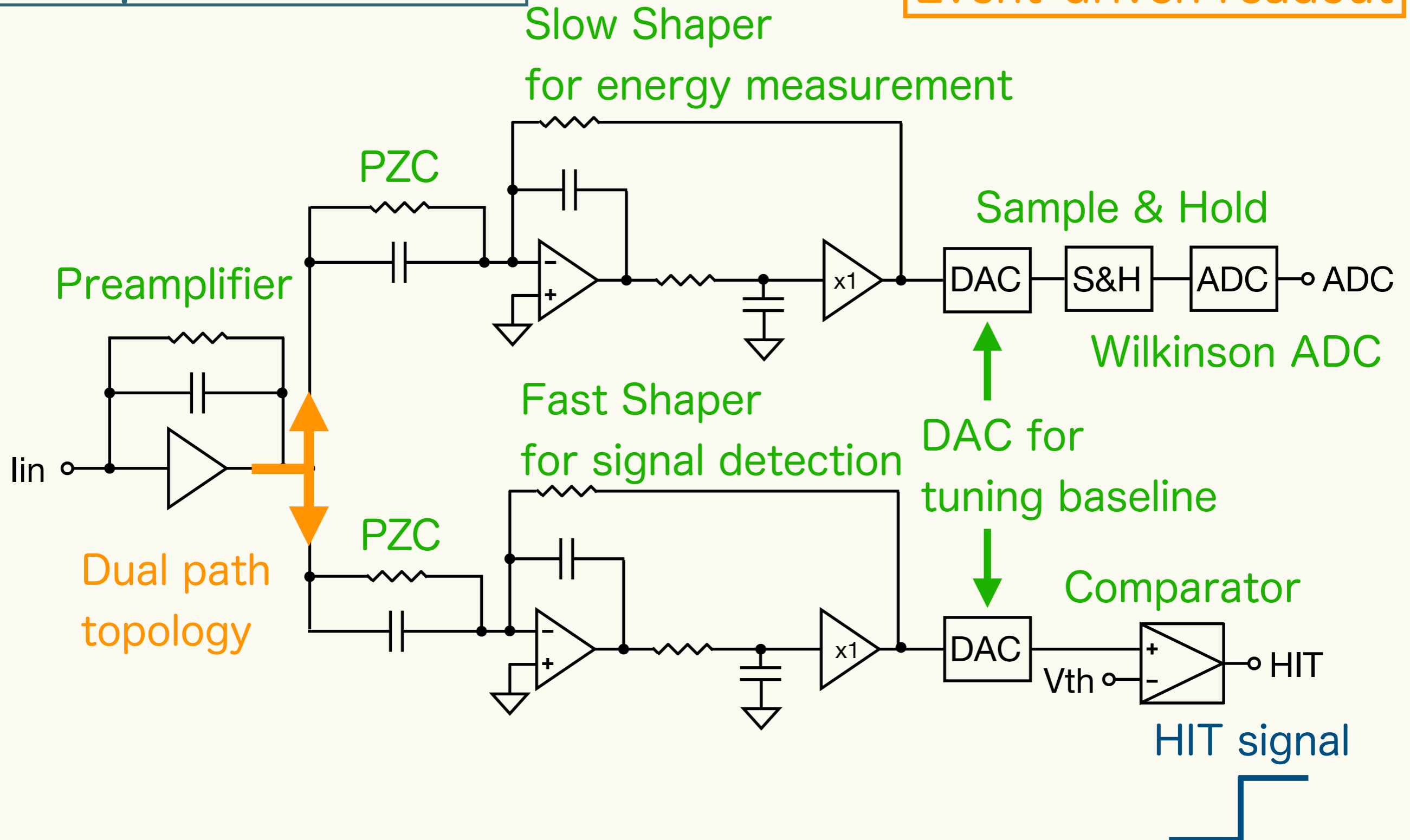


Good
ASIC!!

For High Energy Resolution and Low Threshold

Our previous ASIC

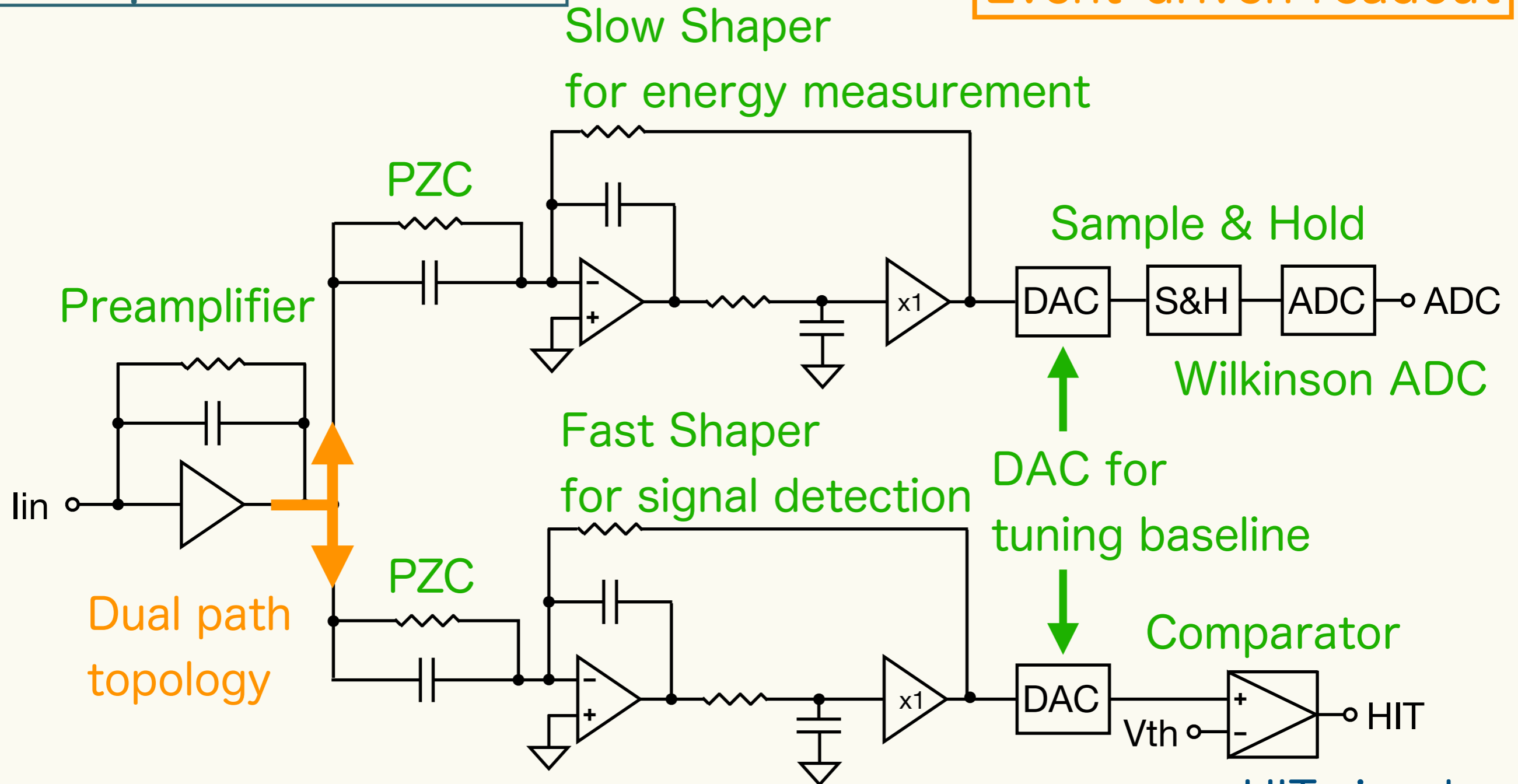
Event-driven readout



For High Energy Resolution and Low Threshold

Our previous ASIC

Event-driven readout



It was hard to investigate the performance of the fast shaper quantitatively.

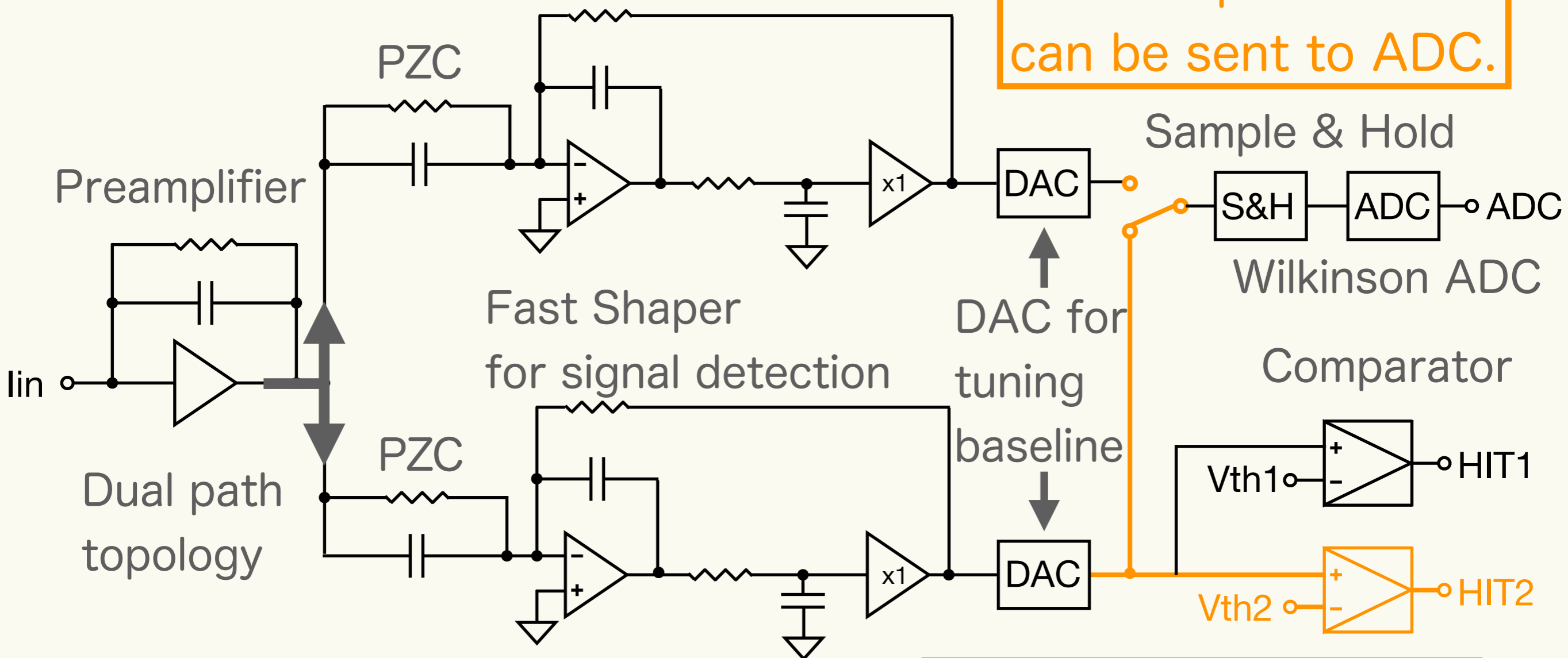
Circuit Design

Our New ASIC

Event-driven readout

Slow Shaper
for energy measurement

Fast shaper
can be sent to ADC.

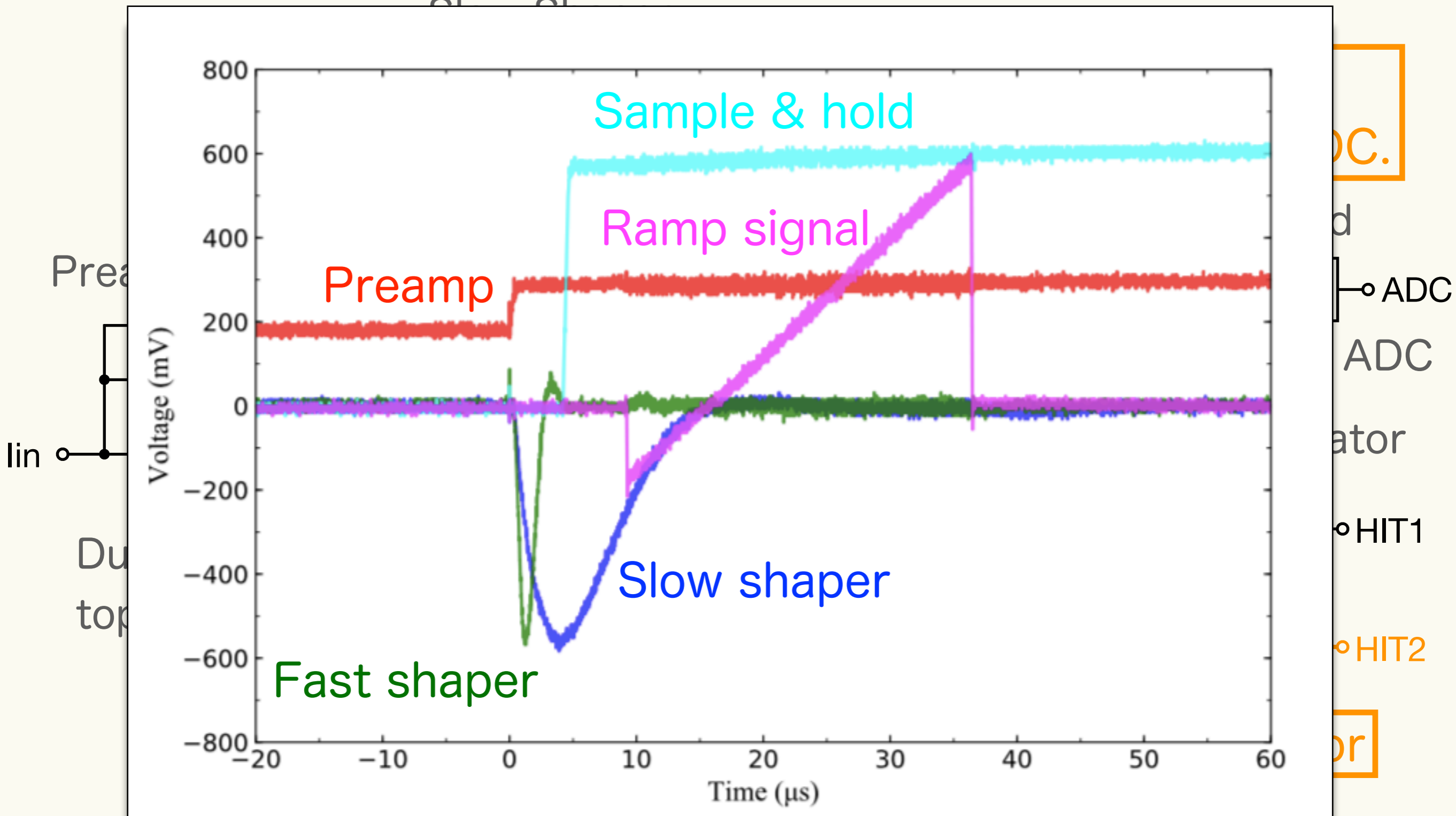


Additional comparator

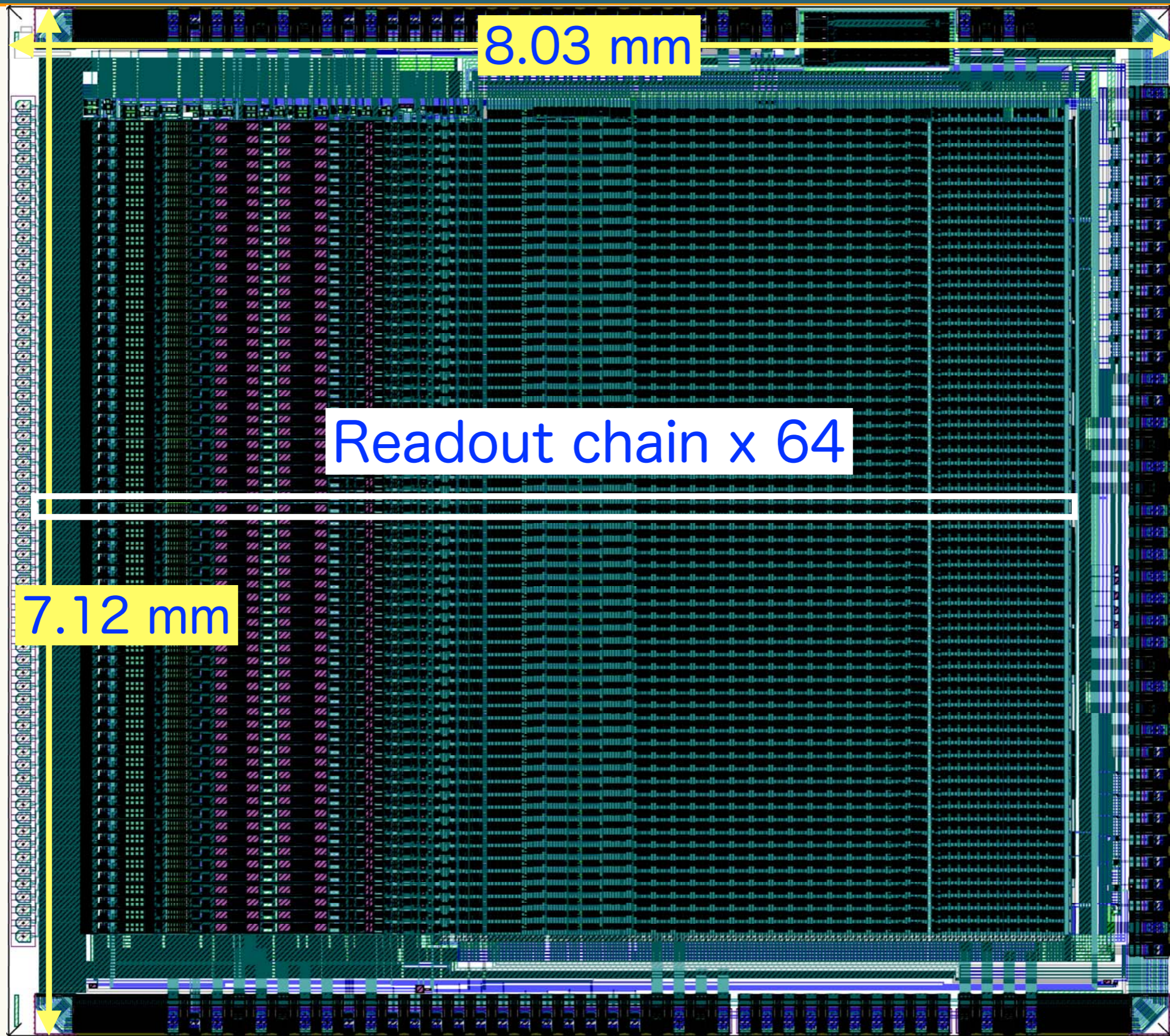
Circuit Design

Our New ASIC

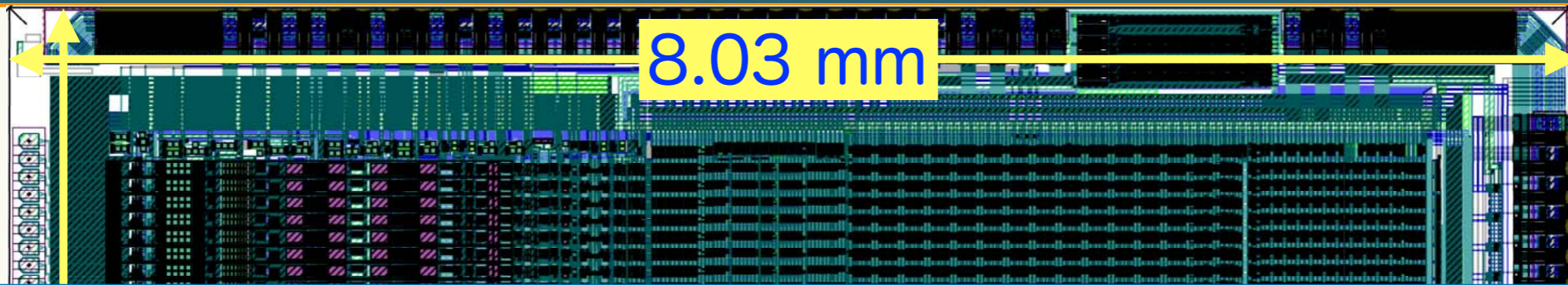
Event-driven readout



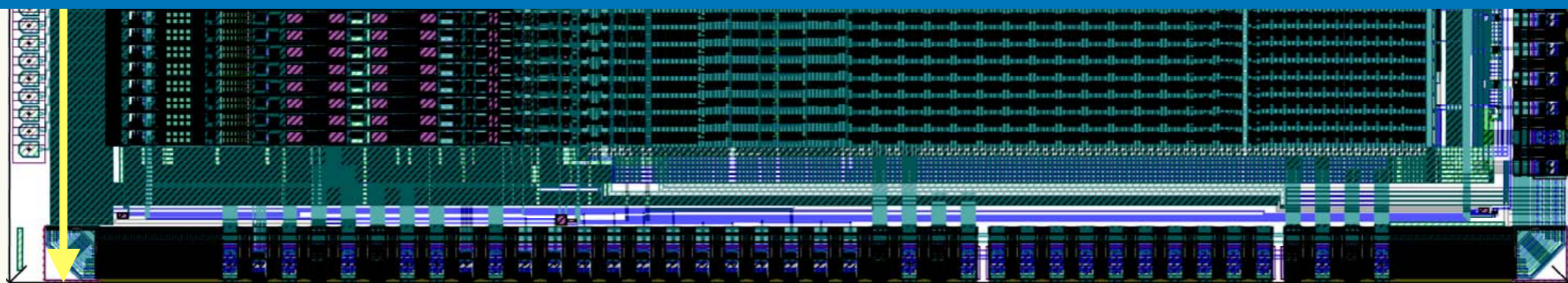
Our Latest ASIC: KW04H64



Our Latest ASIC: KW04H64

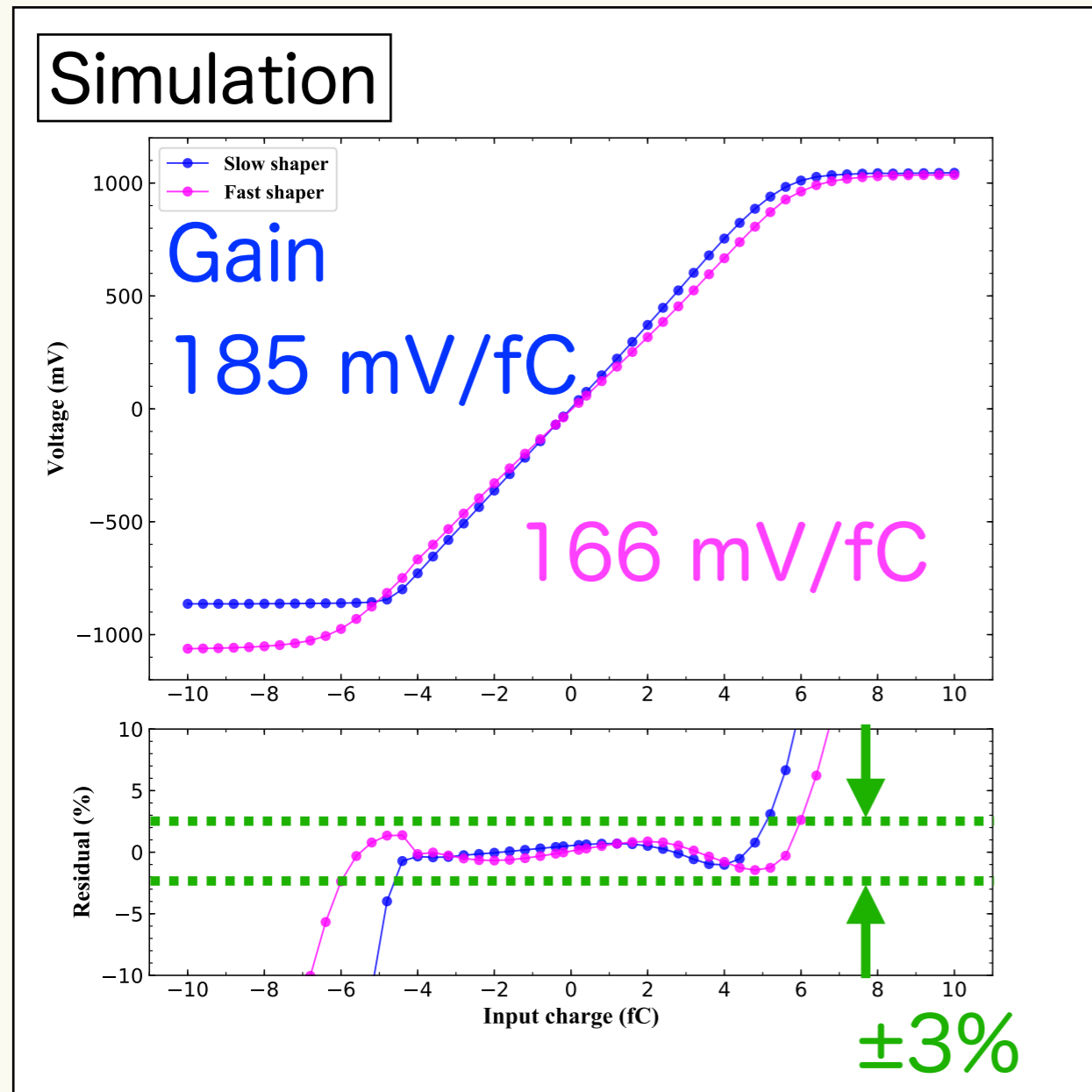


| | |
|---------------------|---------------------------------|
| Fabrication process | X-FAB XH035 (CMOS) |
| Chip size | 7.12 mm × 8.03 mm |
| Number of channels | 64 |
| Power rail | ± 1.65 V |
| Power consumption | 2.1 mW/ch |
| Peaking time | ~ 1.8 us (from simulation) |



ASIC Performance from Simulation

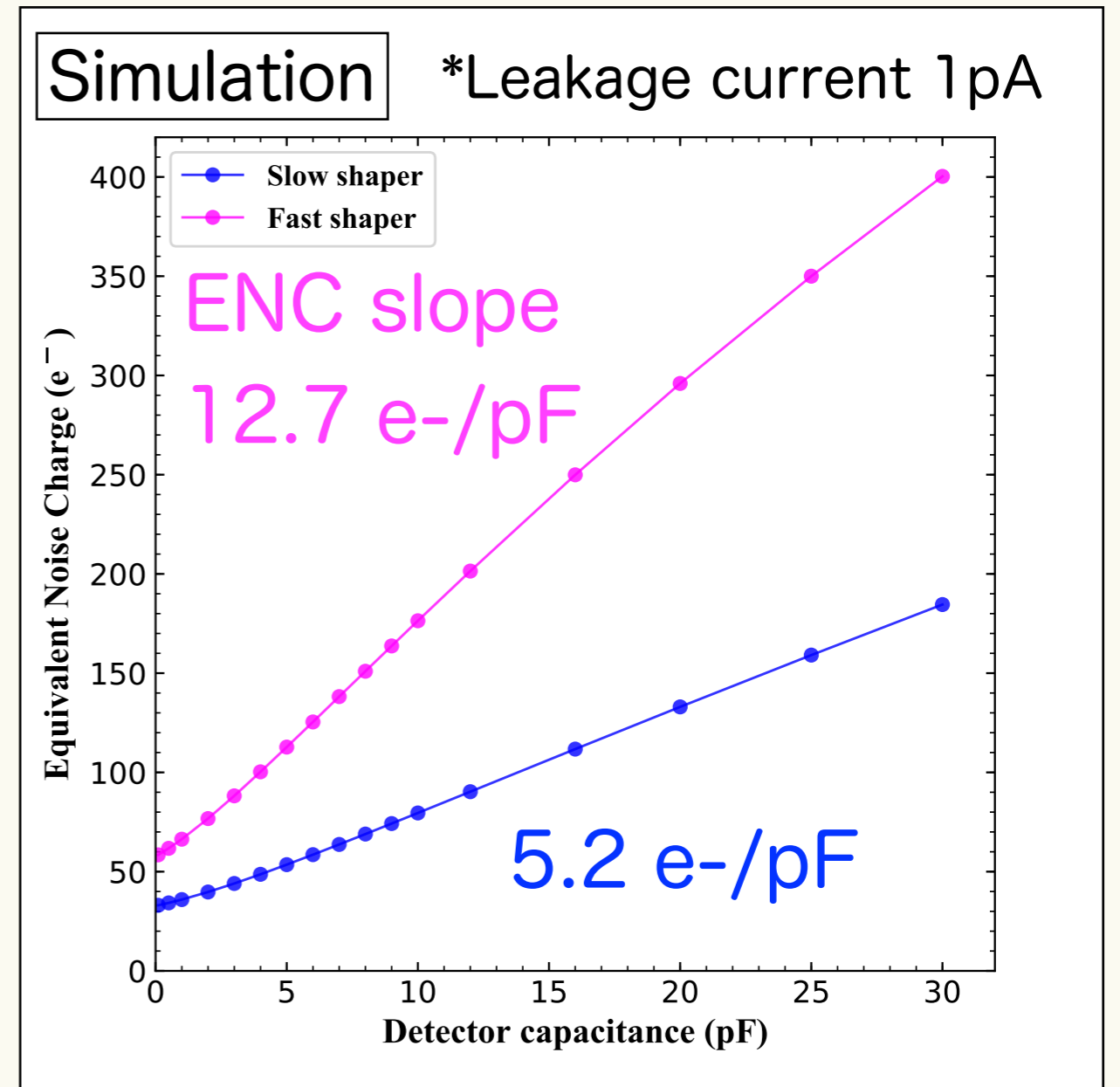
✓ Dynamic range, Linearity



Dynamic range

~32000 e⁻ (for each polarity)

✓ Noise performance



ENC @0 pF load

33.0 e⁻ (Slow shaper)

58.4 e⁻ (Fast shaper)

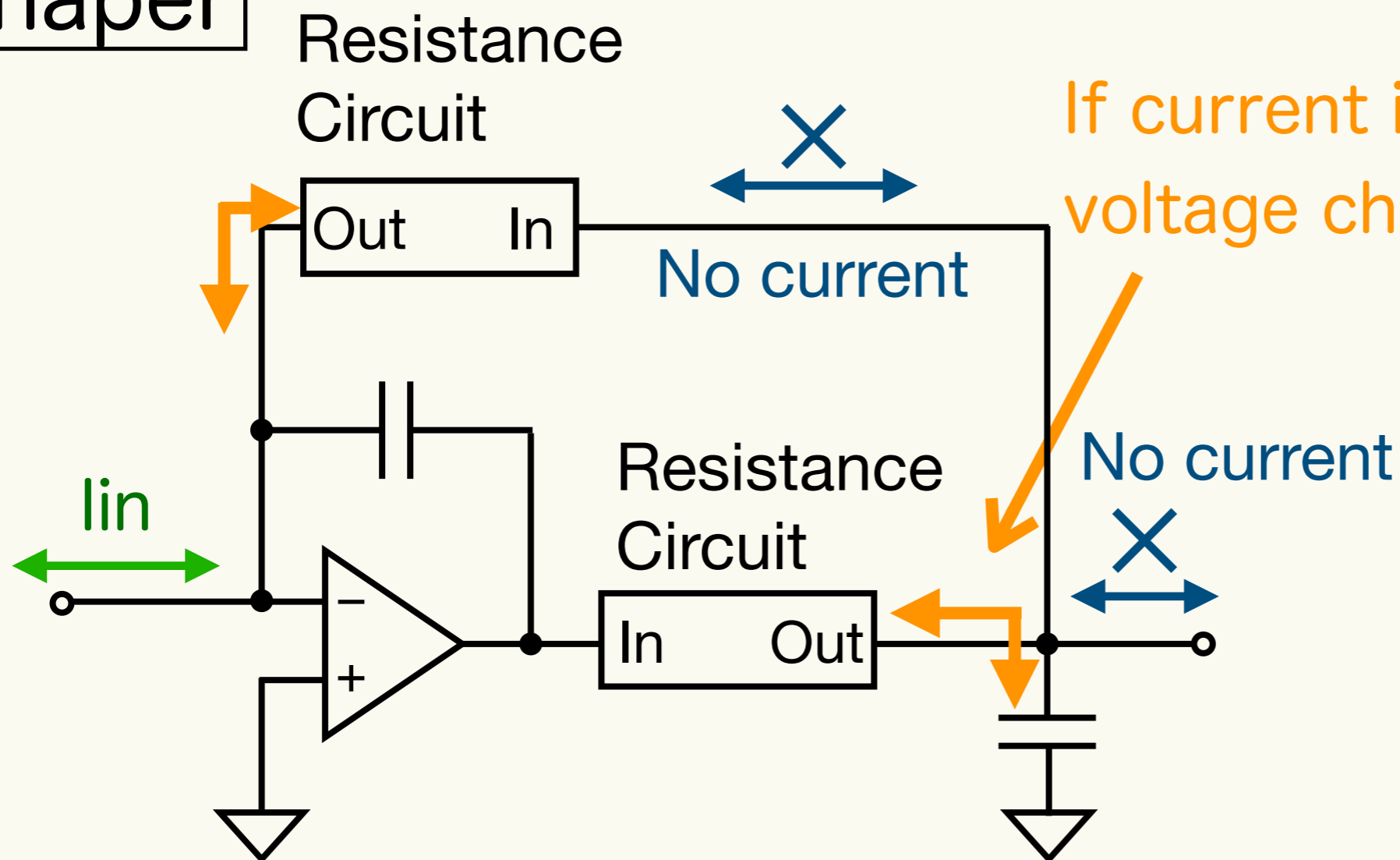
Slew-rate Operation

Required current > Current capable of flowing



Maximum Current flows.

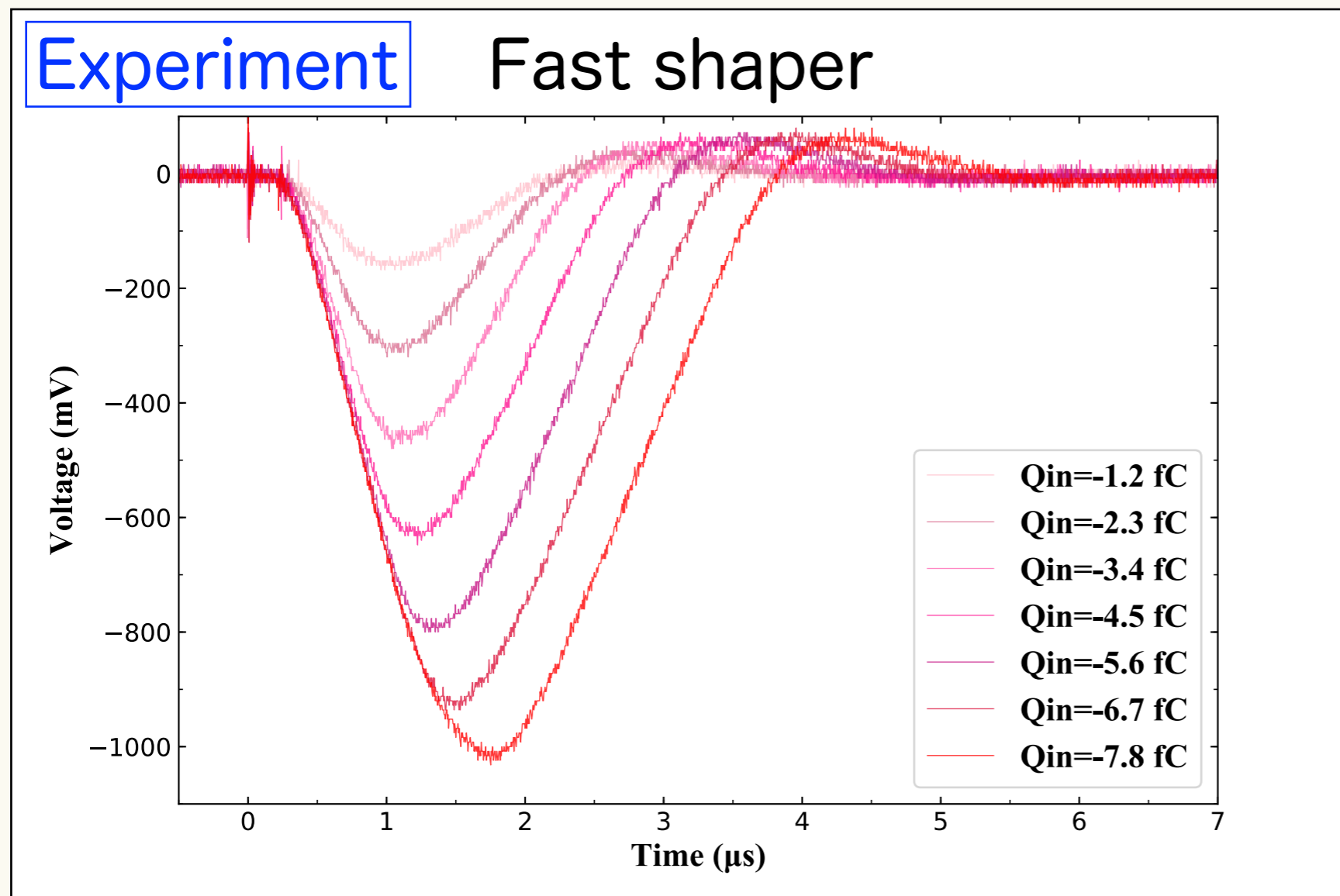
Shaper



If current is constant here, voltage changes linearly.

Slew-rate Operation at Fast Shaper

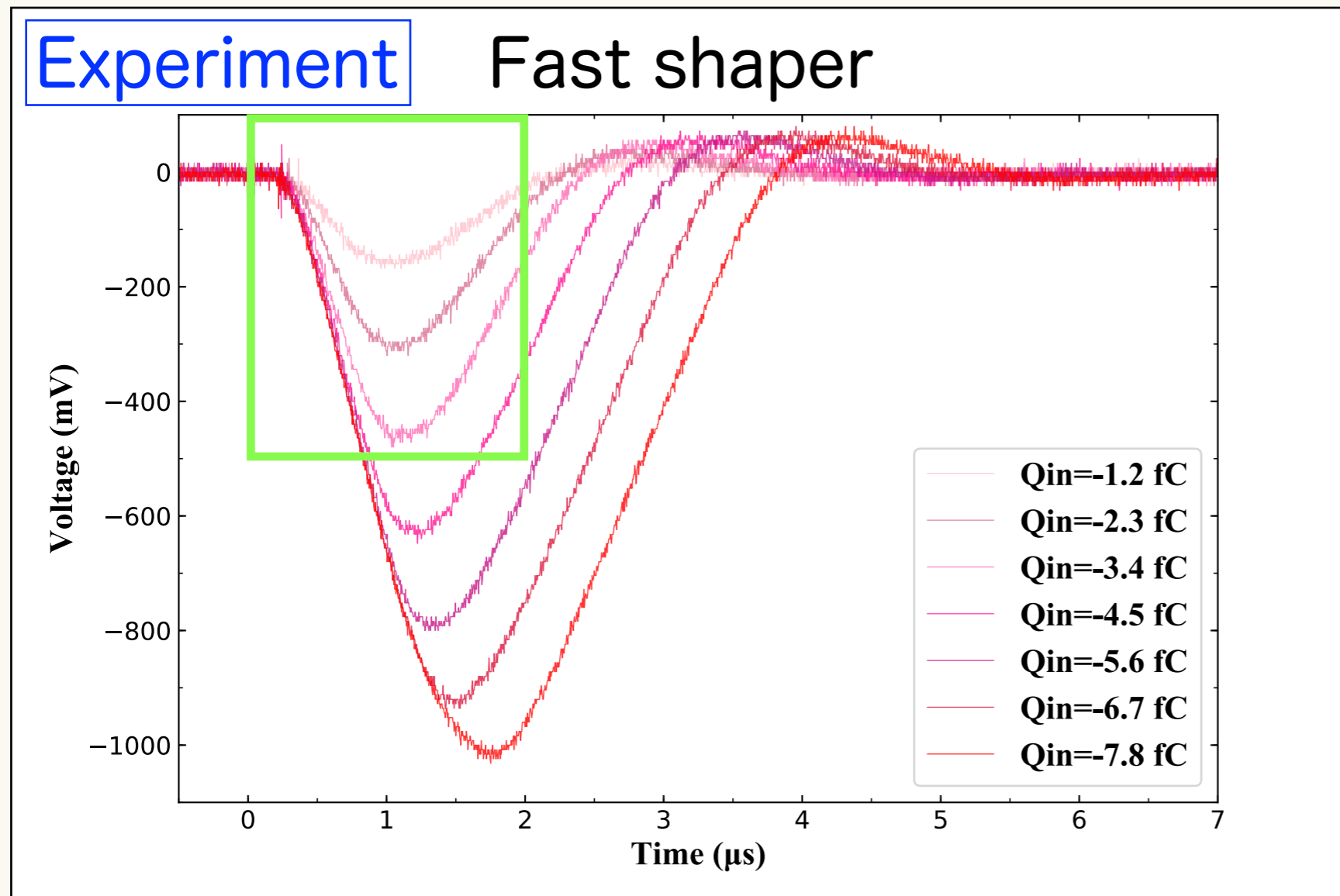
Slew rate operation at fast shaper is essential for insensitivity of trigger timing to input charge.



Accurate timing measurement \longrightarrow Accurate peak capturing

Slew-rate Operation at Fast Shaper

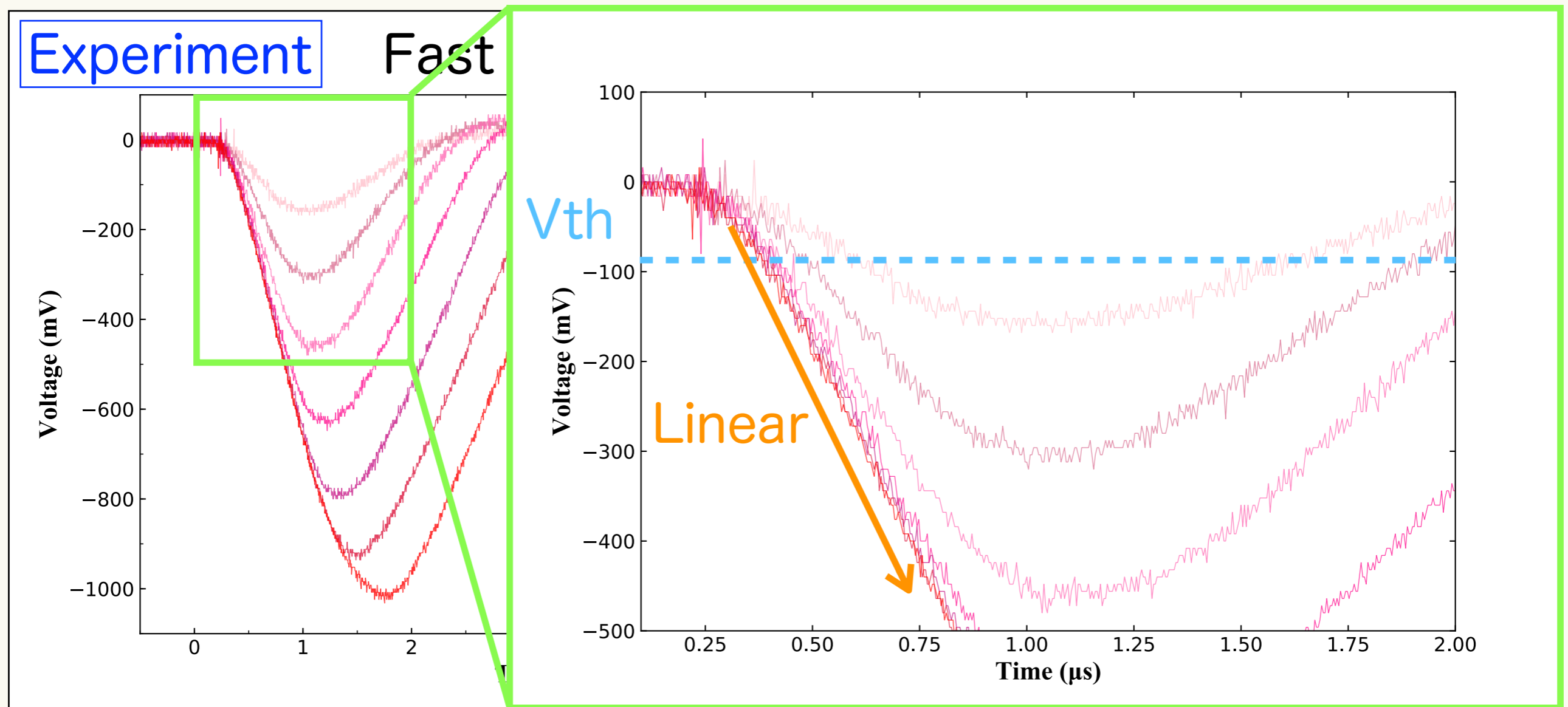
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Accurate timing measurement \longrightarrow Accurate peak capturing

Slew-rate Operation at Fast Shaper

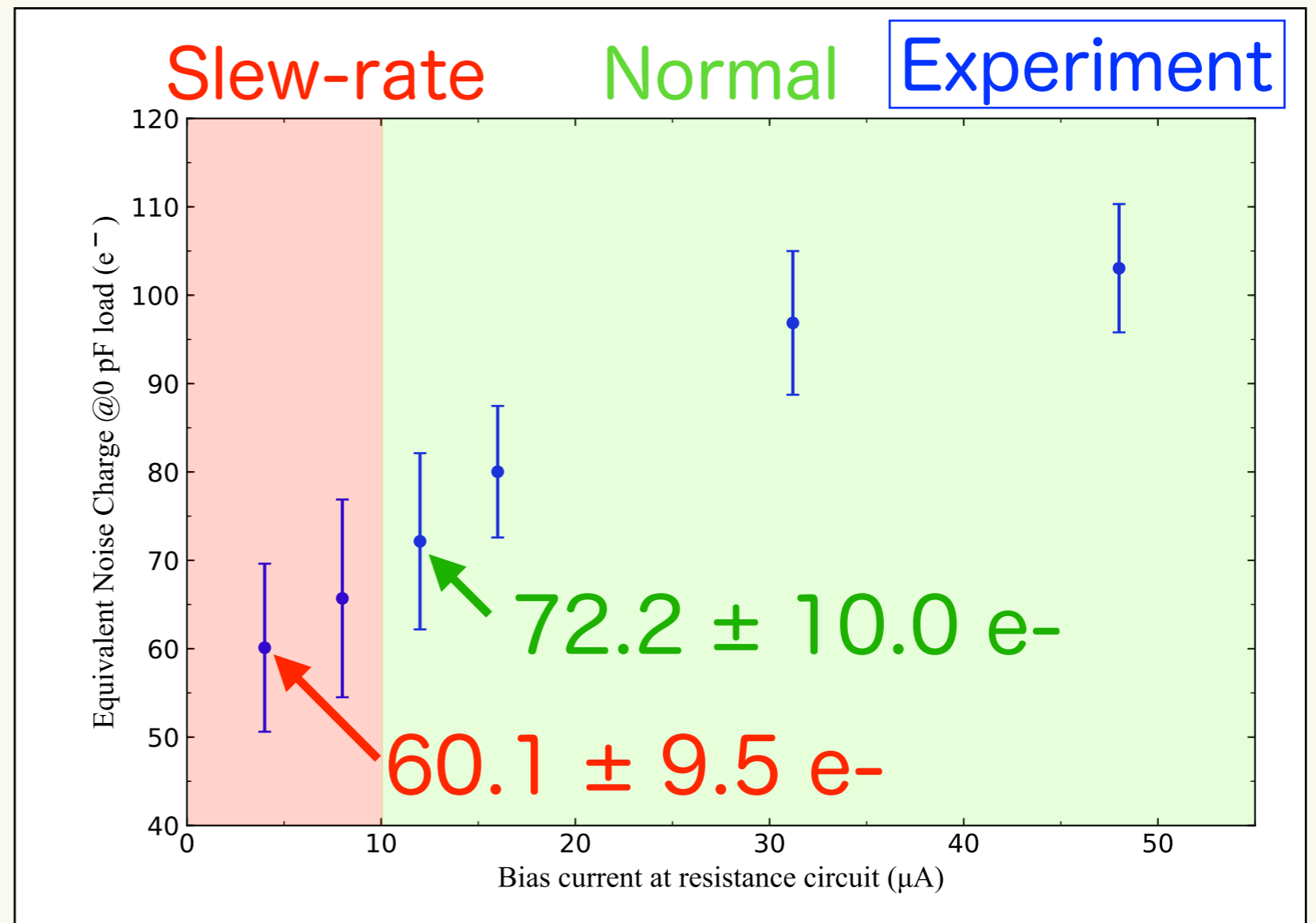
Slew rate operation at fast shaper is essential for insensitivity of trigger timing to input charge.



Accurate timing measurement \longrightarrow Accurate peak capturing

Slew-rate Operation at Slow Shaper

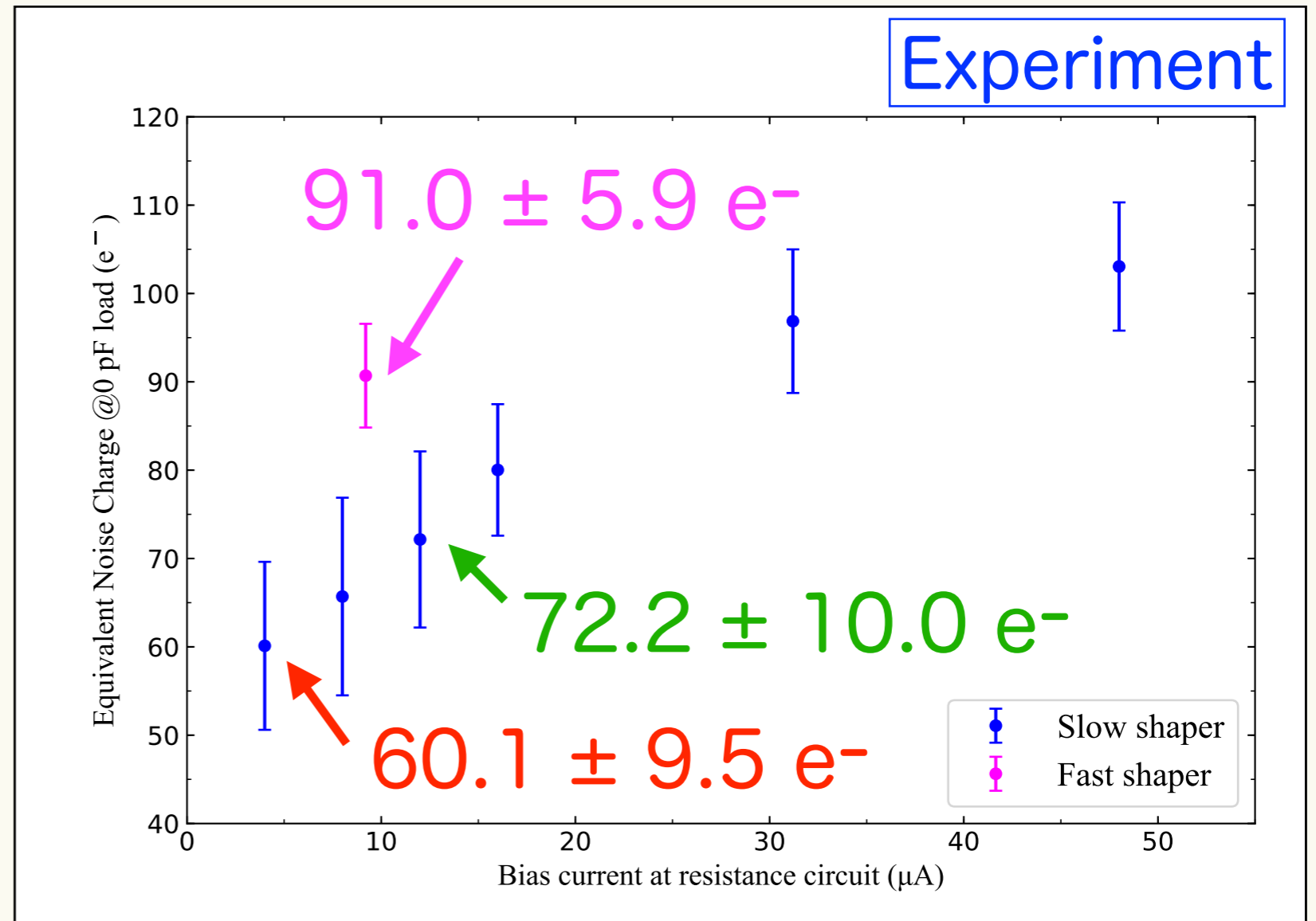
In our circuit, it has turned out that slew-rate operation is also effective for better noise performance. G. Sato et al., 2011



Slew-rate operation improved ENC for $\sim 10 e^-$.

Slew-rate Operation at Slow Shaper

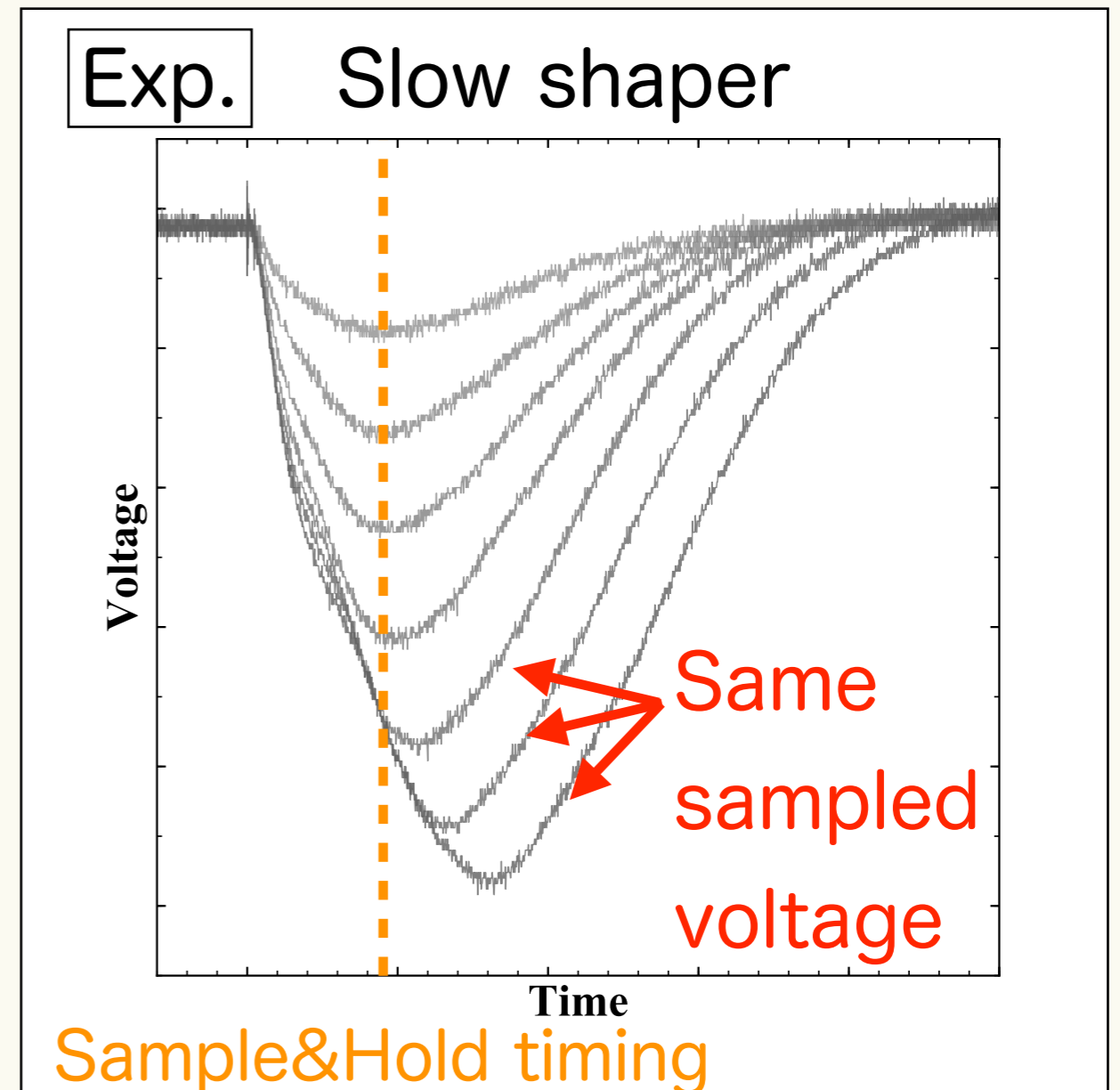
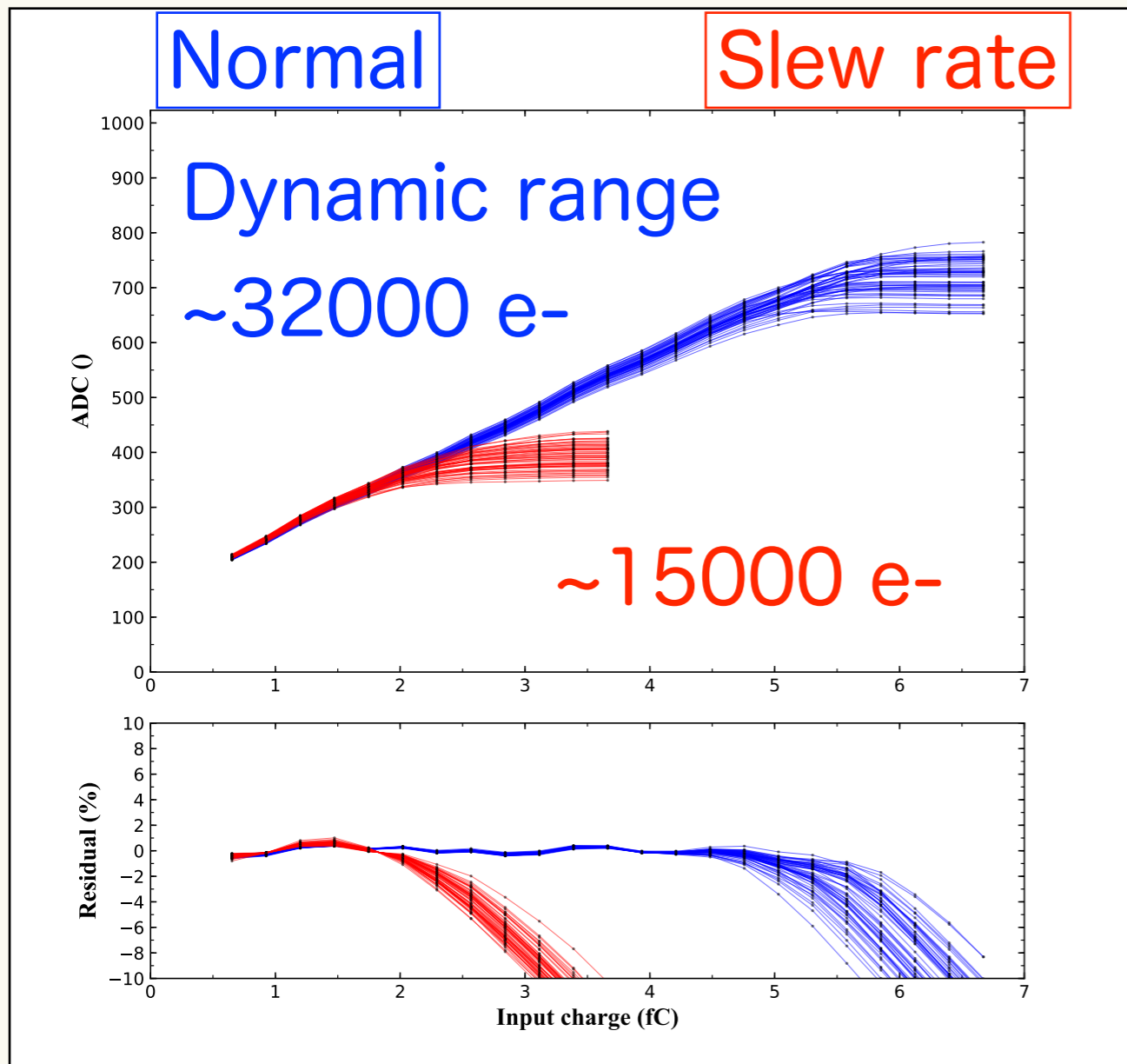
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Slew-rate operation improved ENC for $\sim 10 e^-$.

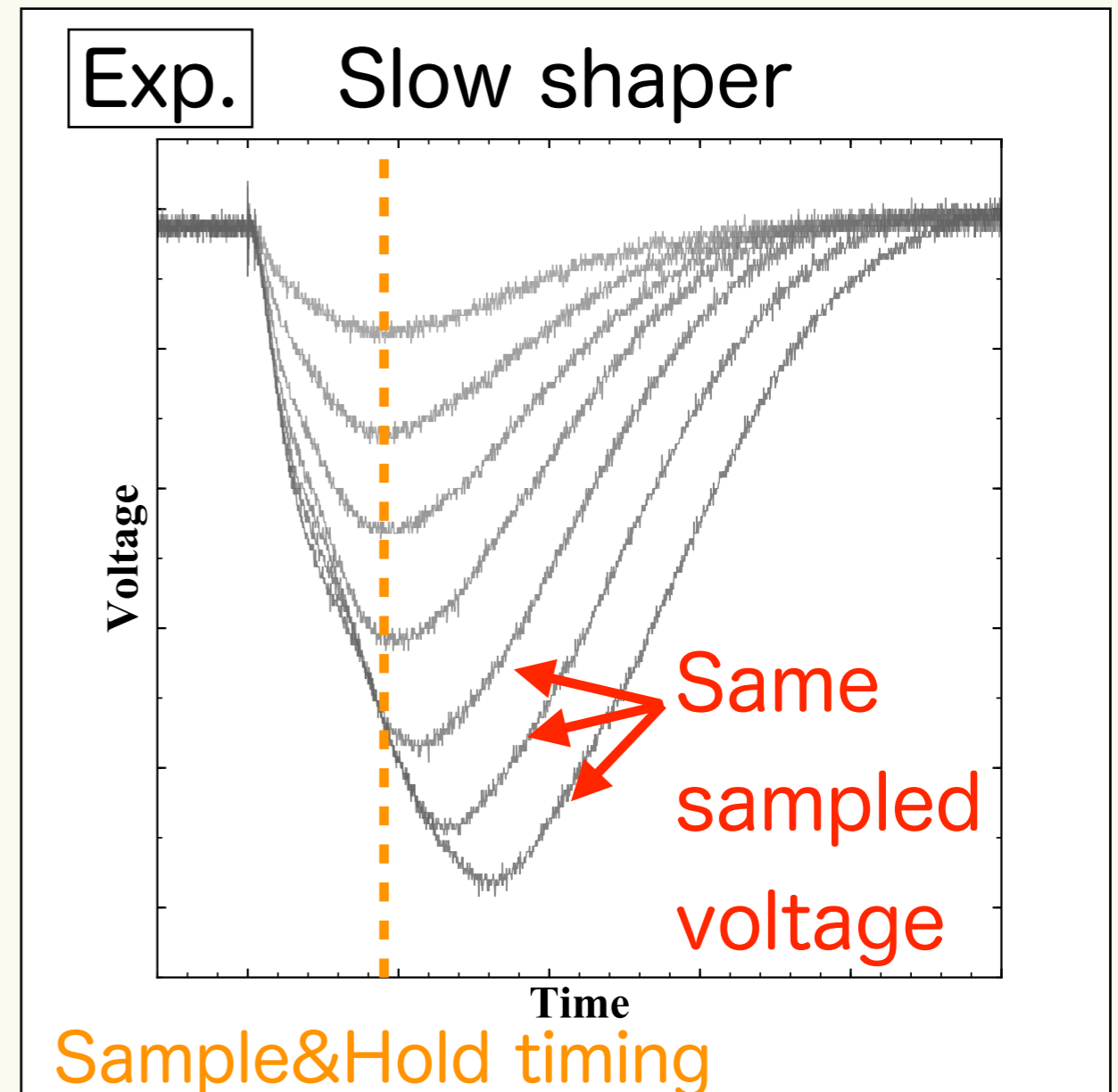
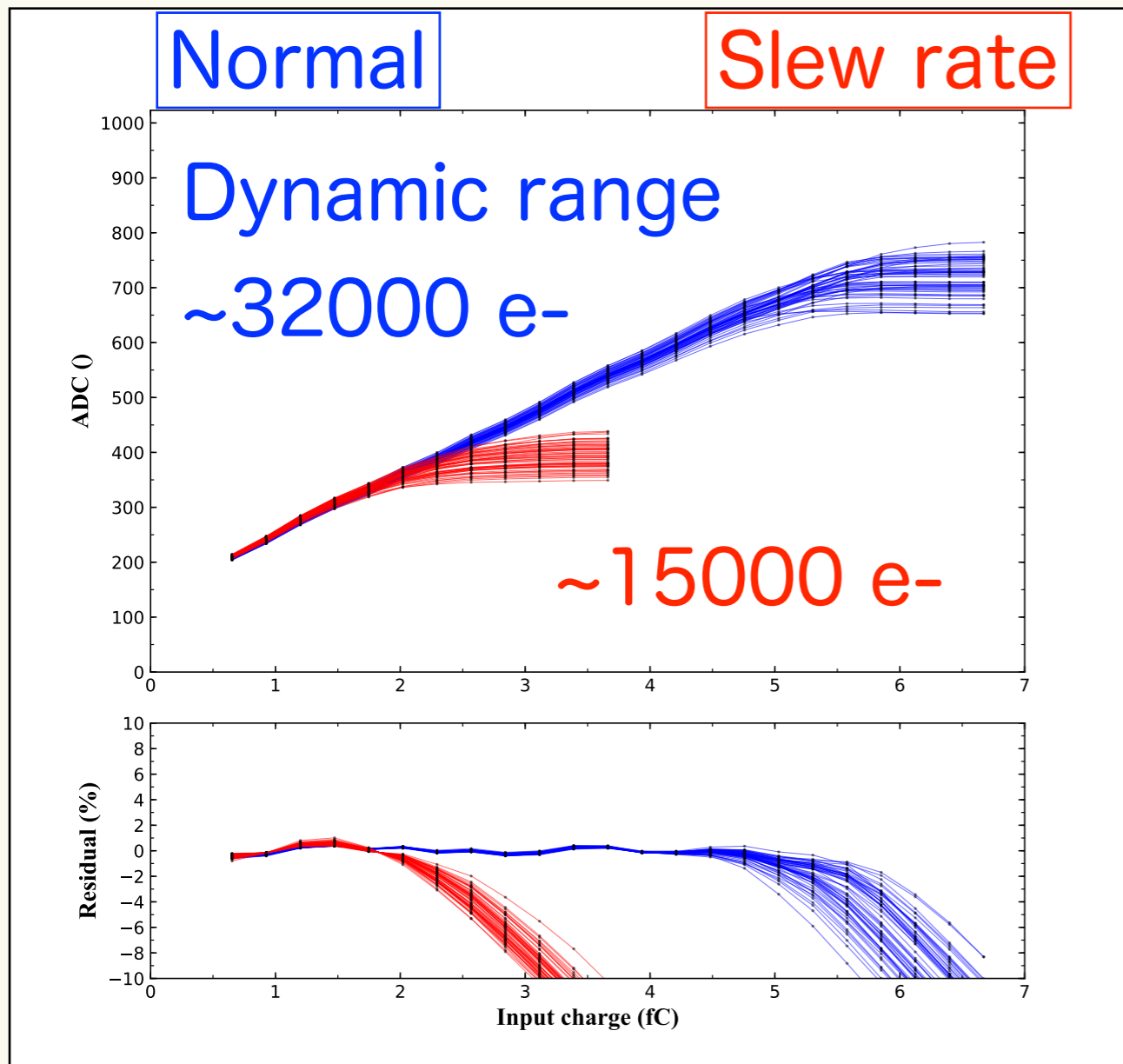
The Problem under Slew-rate Operation

Dynamic range is limited by slew-rate operation as long as sample & hold circuit is employed.



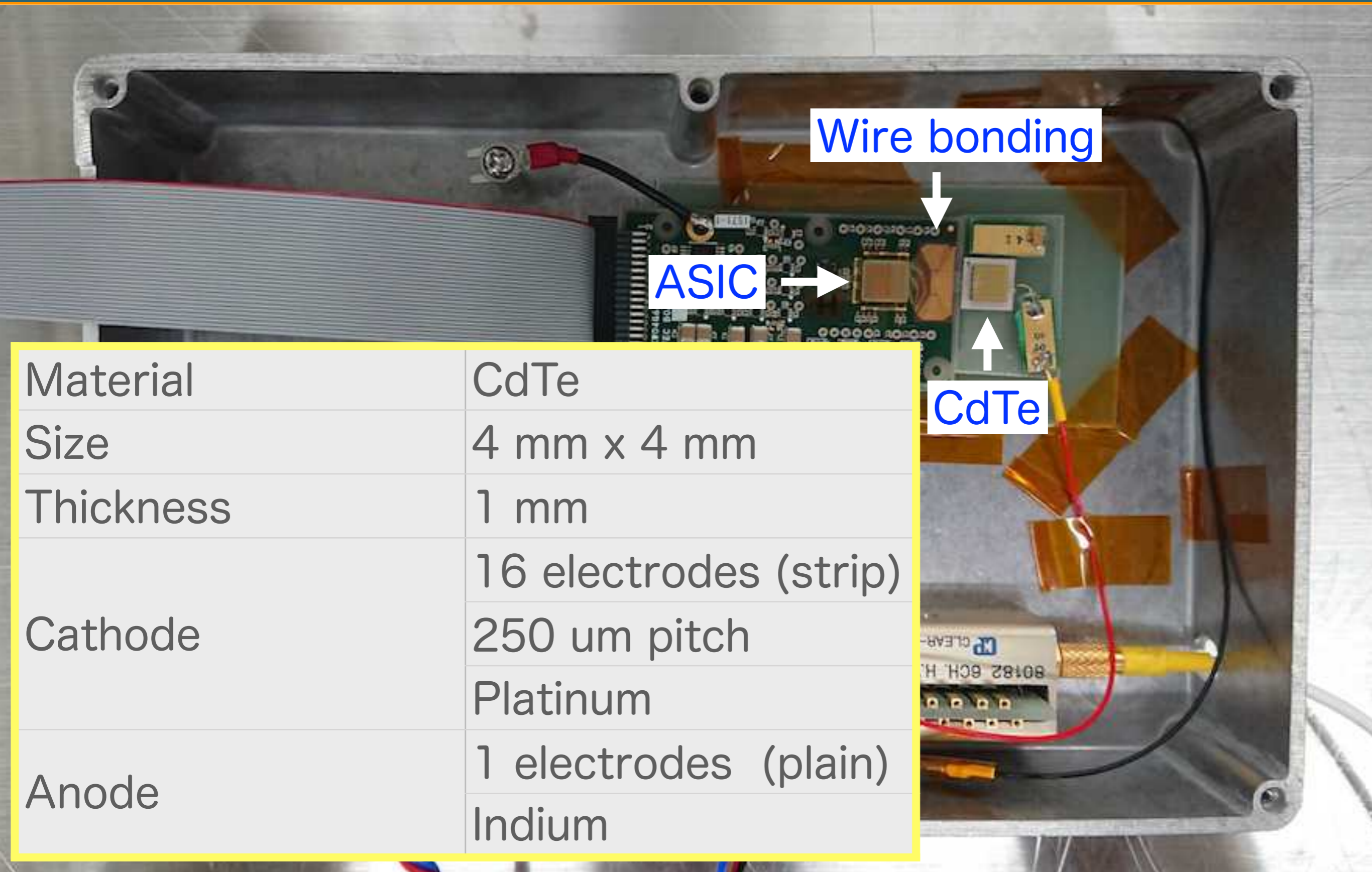
The Problem under Slew-rate Operation

Dynamic range is limited by slew-rate operation as long as sample & hold circuit is employed.



Peak hold circuit is preferred for wider dynamic range under slew-rate operation.

Experimental Setup (Spectroscopy)



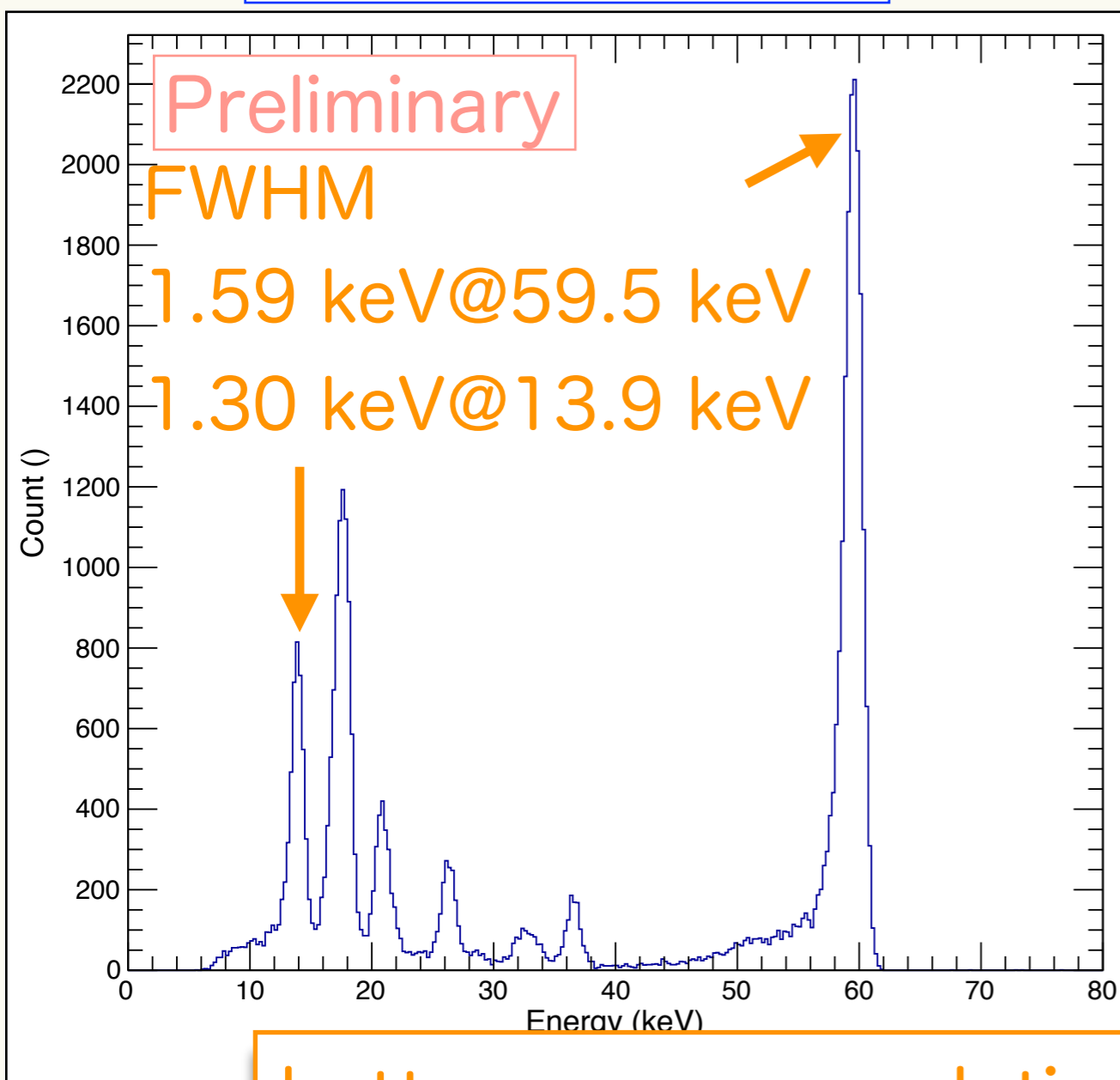
| | |
|-----------|-----------------------|
| Material | CdTe |
| Size | 4 mm x 4 mm |
| Thickness | 1 mm |
| Cathode | 16 electrodes (strip) |
| | 250 um pitch |
| Anode | Platinum |
| | 1 electrodes (plain) |
| | Indium |

Spectrum Measured by Slow Shaper

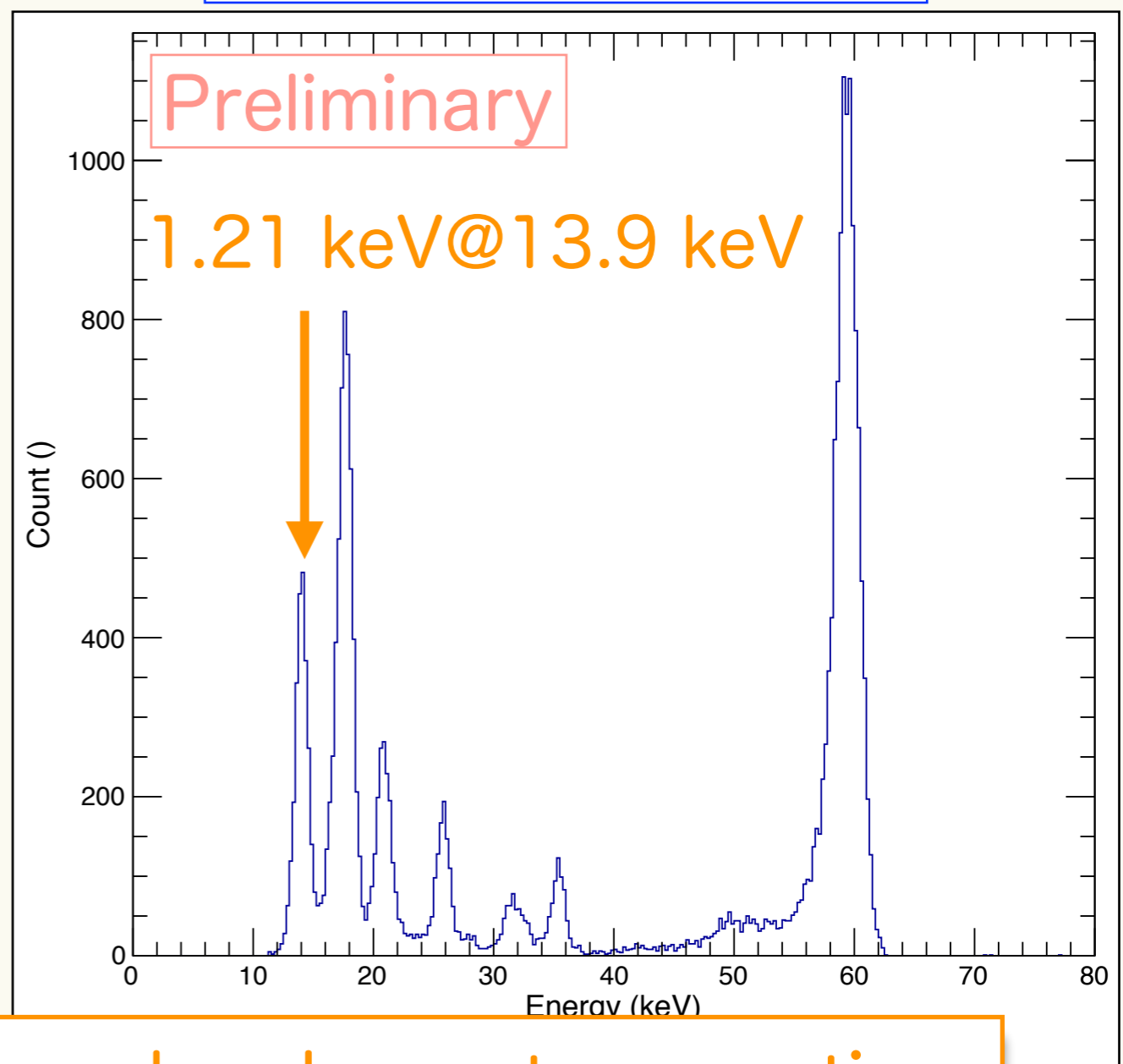
- ❖ Only single hit events were extracted.
- ❖ Results of one channel are shown.

• Am-241 • Temp. -20 °C
• HV 1000V • Cathode

Normal operation



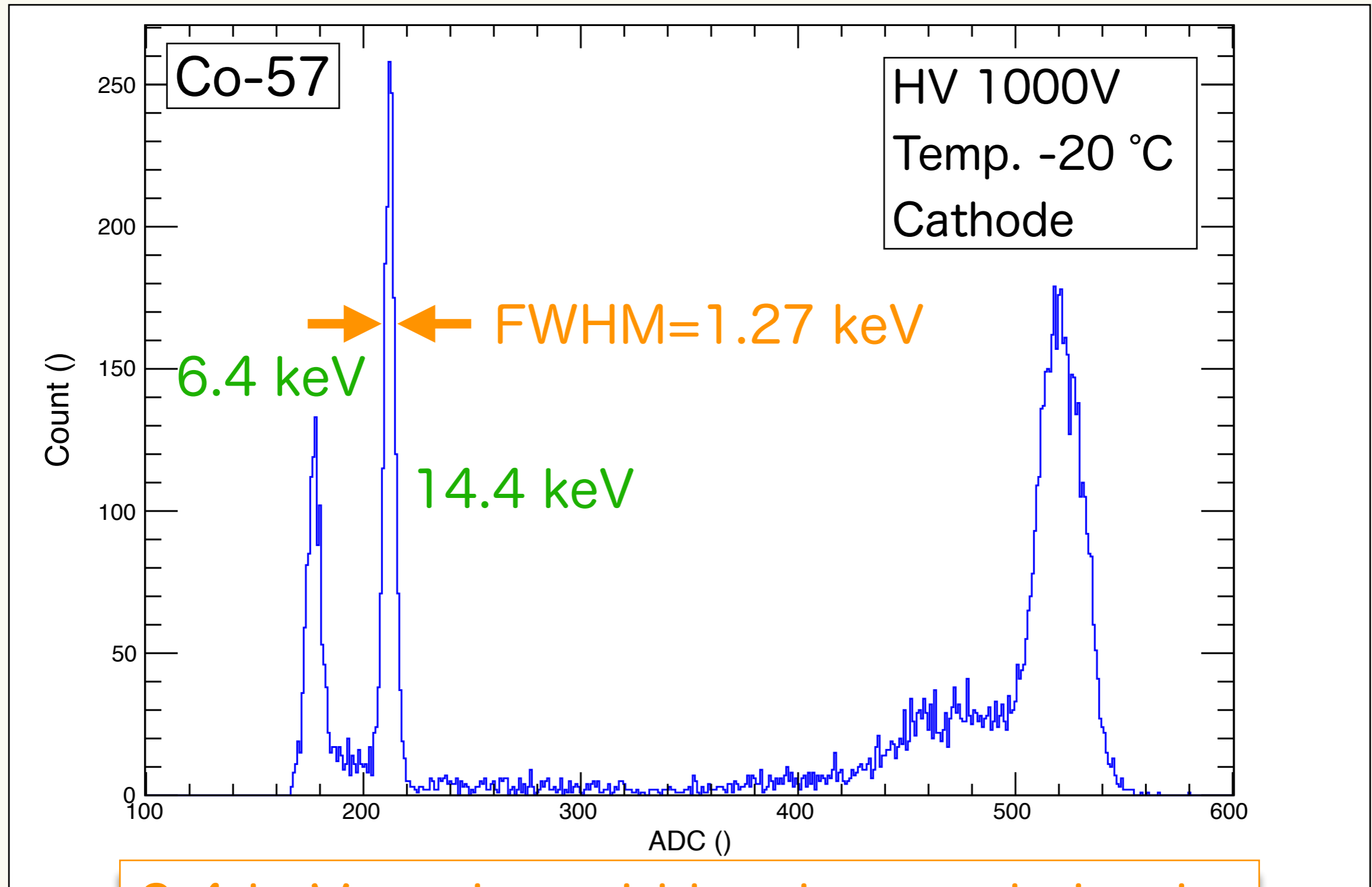
Slew-rate operation



better energy resolution under slew-rate operation.

Spectrum Measured by Fast Shaper

Only single hit events/Result of one channel



6.4 keV peak could be detected clearly.

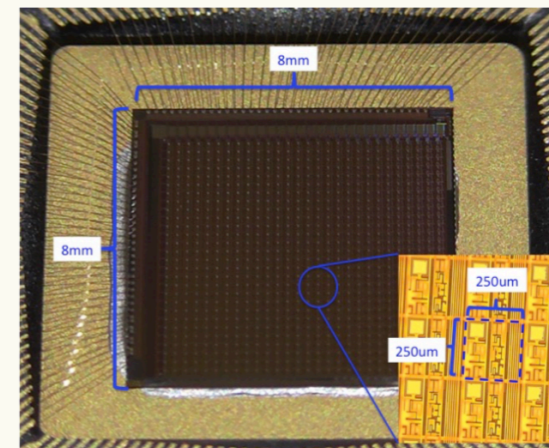
Summary

We have studied readout architectures for hard X-ray and gamma-ray imaging with high spectroscopic capability.

- ❖ Slew rate operation → Better noise performance (~16%)
- ❖ Peak hold circuit enables wide dynamic range under slew-rate operation.
- ❖ We have succeeded in noise evaluation at the fast shaper.

✓ POSTER
@B1F Meeting rooms #5-6

“Development of CdTe
Hybrid Pixel ASIC for
Hard X-ray Imaging”



- TSMC 0.35 um
- 28 x 28 ch
- 250 um pitch
- ENC=50 e-